

EAST Search History

EAST Search History (Prior Art)

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|---------------------|---|------------------|---------|---------------------|
| L1 | 1 | 10/581127 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 12:52 |
| L2 | 2 | ("20050023642").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:53 |
| L3 | 2 | ("20030146468").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:53 |
| L4 | 2 | ("20030146477").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:53 |
| L5 | 2 | ("20020168829").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:54 |
| L6 | 2 | ("20030162360").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:54 |
| L7 | 2 | ("20030219952").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:54 |

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| L8 | 2 | ("6222250").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:54 |
| L9 | 2 | ("4719185").PN. | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2010/06/06 12:55 |
| L10 | 2 | 9 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 12:59 |
| L11 | 2 | 8 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:01 |
| L12 | 1 | "4940671".PN. | USPAT; USOCR | OR | ON | 2010/06/06 13:04 |
| L13 | 2 | 7 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:06 |

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| L14 | 2 | 6 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:06 |
| L15 | 2 | 5 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:39 |
| L16 | 2 | 4 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:40 |
| L17 | 2 | 3 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:42 |

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| L18 | 2 | 2 and (complementary or bipolar or semiconductor or device or collector or emitter or base or region or npn or pnp or transistor or CMOS or FET or doping or type or conductivity or substrate or delimited or silicide or oxide or nitride or silicon or germanium or dry or etching or contact or bipolar) | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:43 |
| L19 | 944 | 257/19 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:43 |
| L20 | 279 | 257/274 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:43 |
| L21 | 3888 | 257/288 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:43 |
| L22 | 212 | 257/279 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
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| L24 | 282 | 257/277 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |

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| L26 | 84 | 257/E21.051 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L27 | 162 | 257/E21.32 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L28 | 37 | 257/E21.115 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L29 | 117 | 257/E21.229 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L30 | 74 | 257/E21.245 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L31 | 132 | 257/E21.267 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:44 |
| L32 | 86 | 257/E21.278 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:45 |

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| L33 | 116 | 257/E21.293 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:45 |
| L34 | 602 | 257/E21.632 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:45 |
| L35 | 31 | "4940671" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2010/06/06 13:45 |

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